

# Yingfen Wei

## List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/8156552/publications.pdf>

Version: 2024-02-01

9

papers

666

citations

1163117

8

h-index

1588992

8

g-index

9

all docs

9

docs citations

9

times ranked

818

citing authors

#	ARTICLE	IF	CITATIONS
1	<i>In situ</i> heating studies on temperature-induced phase transitions in epitaxial Hf <sub>0.5</sub> Zr <sub>0.5</sub> O <sub>2</sub> /La <sub>0.67</sub> Sr <sub>0.33</sub> MnO <sub>3</sub> heterostructures. Applied Physics Letters, 2021, 118, .	3.3	15
2	Reversible oxygen migration and phase transitions in hafnia-based ferroelectric devices. Science, 2021, 372, 630-635.	12.6	138
3	Direct observation of reversible oxygen migration and phase transitions in ferroelectric Hf <sub>0.5</sub> Zr <sub>0.5</sub> O <sub>2</sub> thin-film devices. Microscopy and Microanalysis, 2021, 27, 956-959.	0.4	0
4	Guidelines for the stabilization of a polar rhombohedral phase in epitaxial Hf <sub>0.5</sub> Zr <sub>0.5</sub> O <sub>2</sub> thin films. Ferroelectrics, 2020, 569, 148-163.	0.6	37
5	Magnetic Tunnel Junctions Based on Ferroelectric $\text{Hf}_{0.5}\text{Zr}_{0.5}\text{O}_2$ Ultrathin Films on Silicon. ACS Applied Electronic Materials, 2019, 1, 2585-2593.	4.3	48
6	Negative piezoelectric effect in an organic supramolecular ferroelectric. Materials Horizons, 2019, 6, 1688-1698.	12.2	25
7	Direct Epitaxial Growth of Polar (1 $\times$ 1) HfO <sub>2</sub> / $\text{ZrO}_{2}$ Ultrathin Films on Silicon. ACS Applied Electronic Materials, 2019, 1, 2585-2593.	5.2	34
8	Magneto-ionic control of spin polarization in multiferroic tunnel junctions. Npj Quantum Materials, 2019, 4, .	27.5	324
9	A rhombohedral ferroelectric phase in epitaxially strained Hf <sub>0.5</sub> Zr <sub>0.5</sub> O <sub>2</sub> thin films. Nature Materials, 2018, 17, 1095-1100.		